

LET9120M

RF power transistor from the LdmoST family of n-channel enhancement-mode lateral MOSFETs

Preliminary data

Features

- Excellent thermal stability
- Common source configuration push-pull
- P_{OUT} = 120 W with 18 dB gain @ 860 MHz
- Internal input matching
- BeO-free package

Description

The LET9120M is a common source n-channel enhancement-mode lateral field-effect RF power transistor designed for broadband commercial and industrial applications at frequencies up to 1.0 GHz.

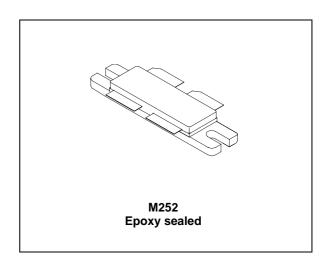


Figure 1. Pin connection

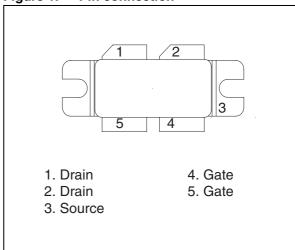


Table 1. Device summary

Order code	Package	Branding
LET9120M	M252	LET9120M

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LET9120M Electrical data

1 Electrical data

1.1 Maximum ratings

Table 2. Absolute maximum ratings ($T_{CASE} = 25 \, ^{\circ}C$)

Symbol	Parameter	Value	Unit
V _{(BR)DSS}	Drain-source voltage	80	V
V_{GS}	Gate-source voltage	±20	V
I _D	Drain current	18	Α
P _{DISS}	Power dissipation (@ Tc = 70°C)	217	W
T _J	Max. operating junction temperature	200	°C
T _{STG}	Storage temperature -65 to +150		°C

1.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Junction - case thermal resistance	0.6	°C/W

2 Electrical characteristics

$$T_{CASE} = +25$$
 °C

2.1 Static

Table 4. Static (per section)

Symbol		Min	Тур	Max	Unit		
V _{(BR)DSS}	$V_{GS} = 0 V$	$I_{DS} = 10 \text{ mA}$	I _{DS} = 10 mA				V
I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 28 V	V _{DS} = 28 V			1	μΑ
I _{GSS}	$V_{GS} = 5 V$	$V_{DS} = 0 V$				1	μΑ
V _{GS(Q)}	V _{DS} = 28 V	$I_D = 100 \text{ mA}$	I _D = 100 mA			5.0	V
V _{DS(ON)}	V _{GS} = 10 V	I _D = 3 A			0.9	1.2	V
G _{FS}	V _{DS} = 10 V	I _D = 3 A	I _D = 3 A				mho
C _{OSS}	$V_{GS} = 0 V$	$V_{DS} = 28 \text{ V}$	f = 1 MHz		29		pF

Note: Device is internally input matched.

2.2 Dynamic

Table 5. Dynamic

Symbol	Test conditions	Min	Тур	Max	Unit
P _{OUT}	$V_{DD} = 32 \text{ V}$ $I_{DQ} = 400 \text{ mA}$ $f = 860 \text{ MHz}$	120			W
G _{PS}	$V_{DD} = 32 \text{ V}$ $I_{DQ} = 400 \text{ mA}$ $P_{OUT} = 120 \text{ W}$ f = 860 MHz	16	18	-	dB
η	$V_{DD} = 32 \text{ V}$ $I_{DQ} = 400 \text{ mA}$ $P_{OUT} = 120 \text{ W}$ f = 860 MHz	50	65		%

3 Package mechanical data

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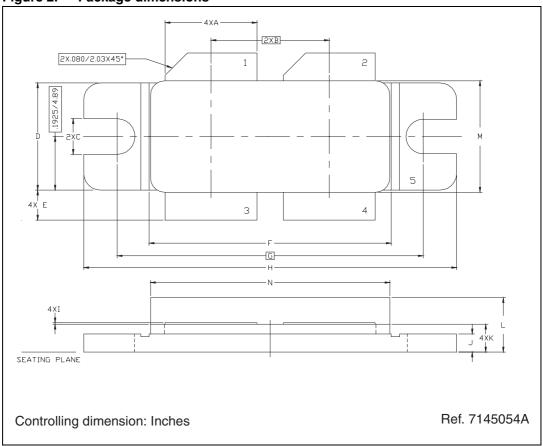
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Table 6. M252 (.400 x .860 4L BAL N/HERM W/FLG) mechanical data

Dim.	mm. inch					
	Min	Тур	Max	Min	Тур	Max
Α	8.13		8.64	.320		.340
В		10.80			.425	
С	3.00		3.30	.118		.130
D	9.65		9.91	.380		.390
Е	2.16		2.92	.085		.115
F	21.97		22.23	.865		.875
G		27.94			1.100	
Н	33.91		34.16	1.335		1.345
I	0.10		0.15	.004		.006
J	1.52		1.78	.060		.070
K	2.36		2.74	.093		.108
L	4.57		5.33	.180		.210
М	9.96		10.34	.392		.407
N	21.64		22.05	.852		.868

Figure 2. Package dimensions



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LET9120M Revision history

4 Revision history

Table 7. Document revision history

Date	Revision	Changes
10-Nov-2009	1	First Issue.
11-Feb-2010	2	Changed test condition for V _{(BR)DSS} in <i>Table 4: Static (per section)</i> .

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